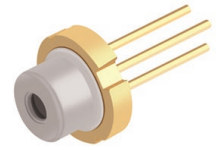


PLT5 520EA_P

Metal Can® TO56

Green Laser Diode in TO56 Package



Applications

- Architecture / Garden Lighting (LED & Laser)
- Area Lights
- Downlights/Spotlights
- Mood Lighting
- Street, Tunnel and Outdoor

Features:

- Optical output power (continuous wave): 20 mW ($T_{case} = 25^{\circ}C$)
- Typical emission wavelength: 520 nm
- Efficient radiation source for cw and pulsed operation
- Single transverse mode semiconductor laser
- High modulation bandwidth
- TO56 package with photo diode

Ordering Information

Type	Peak output power typ. P_{opt}	Ordering Code
PLT5 520EA_P	20 mW	TBD

DRAFT – For reference only. Subject to change without notice.

Maximum Ratings

$T_C = 25\text{ °C}$

Parameter	Symbol		Values
Operating temperature	T_{op}	min.	-20 °C
		max.	60 °C
Storage temperature	T_{stg}	min.	-40 °C
		max.	85 °C
Junction temperature	T_j	max.	120 °C
Forward current ¹⁾	I_F	max.	200 mA
Reverse voltage ²⁾	V_R	max.	2 V
Soldering temperature	T_S	max.	260 °C

$t_{max} = 10\text{ s}$

Operation outside these conditions may damage the device. Operation at maximum ratings may influence lifetime.

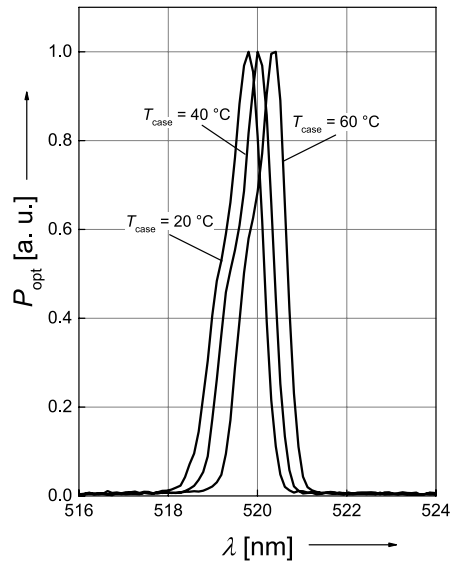
Characteristics

$P_{\text{opt}} = 20 \text{ mW}$; $T_{\text{case}} = 25 \text{ °C}$

Parameter	Symbol	Values
Forward current ¹⁾	I_{F}	typ. 65 mA max. 105 mA
Peak wavelength ³⁾	λ_{peak}	min. 510 nm typ. 520 nm max. 530 nm
Spectral bandwidth at 50% $I_{\text{e,rel,max}}$	$\Delta\lambda$	typ. 1 nm
Beam divergence (FWHM) parallel to pn-junction	Θ_{\parallel}	min. 5 ° typ. 6.6 ° max. 8 °
Beam divergence (FWHM) perpendicular to pn-junction	Θ_{\perp}	min. 19 ° typ. 21.4 ° max. 25 °
Monitor current ⁴⁾⁵⁾ $V_{\text{R}} = 5 \text{ V}$	I_{m}	typ. 150 μA
Threshold current	I_{th}	typ. 35 mA max. 65 mA
Forward voltage ⁶⁾	V_{F}	typ. 6.2 V max. 7.5 V
TE polarization	P_{TE}	typ. 100:1
Modulation frequency	f	min. 100 MHz
Thermal resistance junction case real	R_{thJC}	typ. 34 K / W

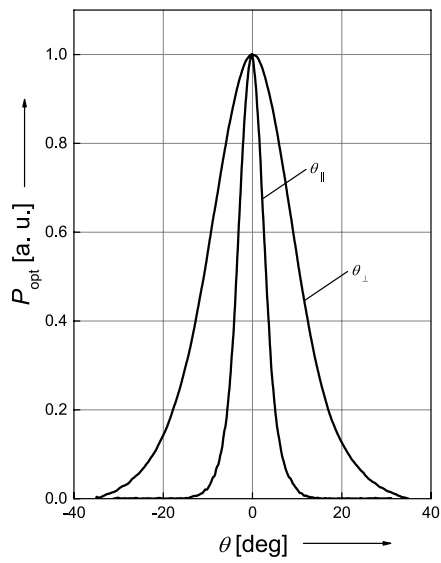
Relative Spectral Emission 7), 8)

$$I_{e,rel} = f(\lambda); I_F = 60 \text{ mA}; P_{opt} = 20 \text{ mW}$$



Beam Divergence 7), 8)

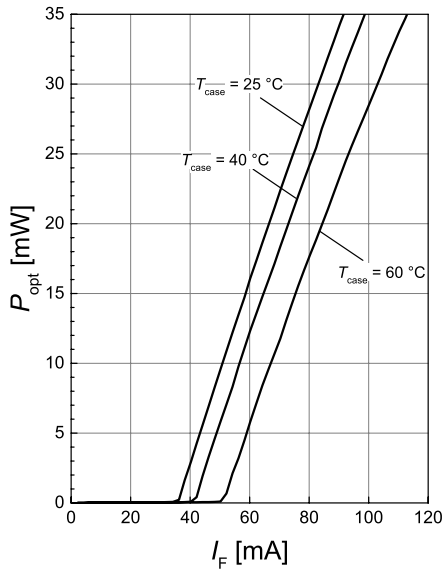
$$P_{opt} = f(\Theta)$$



DRAFT – For reference only. Subject to change without notice.

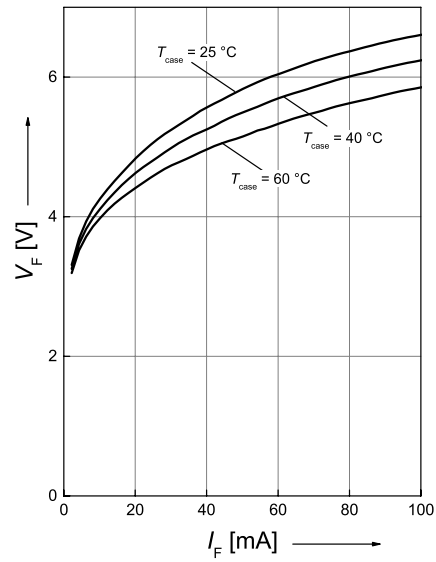
Optical Output Power 7), 8)

$$P_{opt} = f(I_F)$$



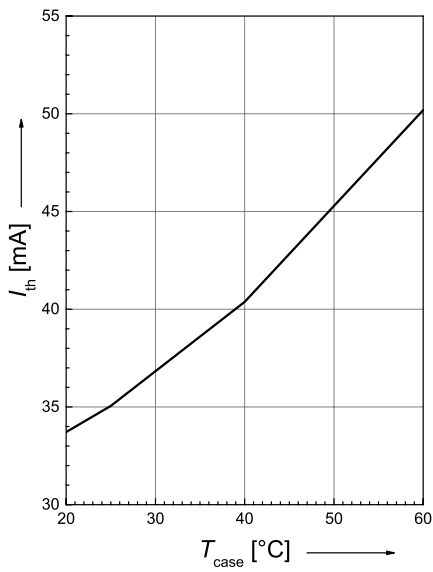
Opt. Power / Forward Voltage 7), 8)

$$V_F = f(I_F)$$



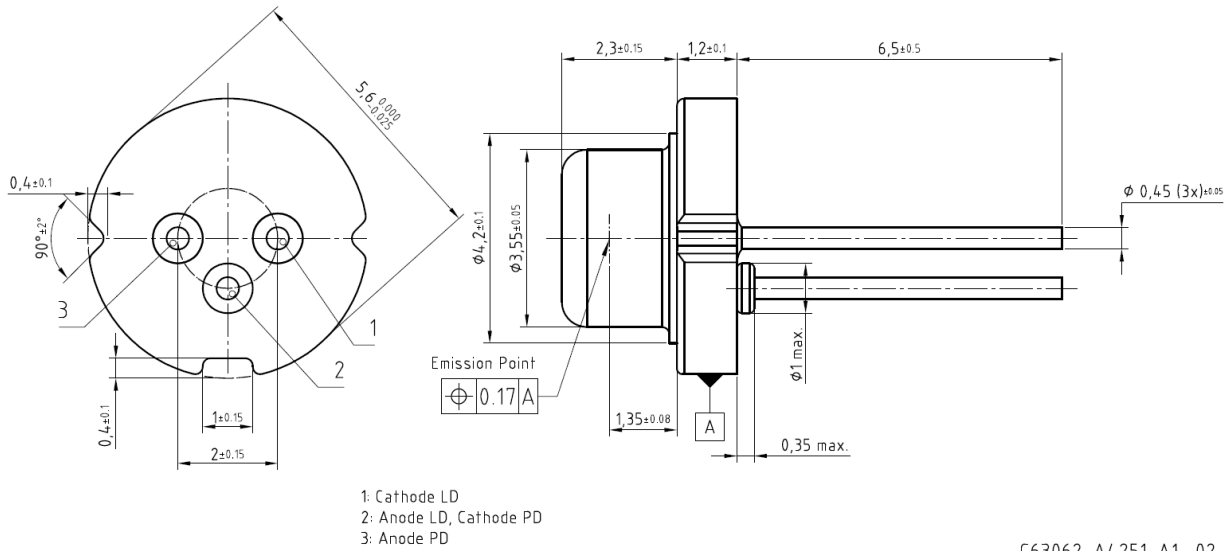
Threshold Current

$$I_F = f(T)$$



DRAFT – For reference only. Subject to change without notice.

Dimensional Drawing ⁹⁾

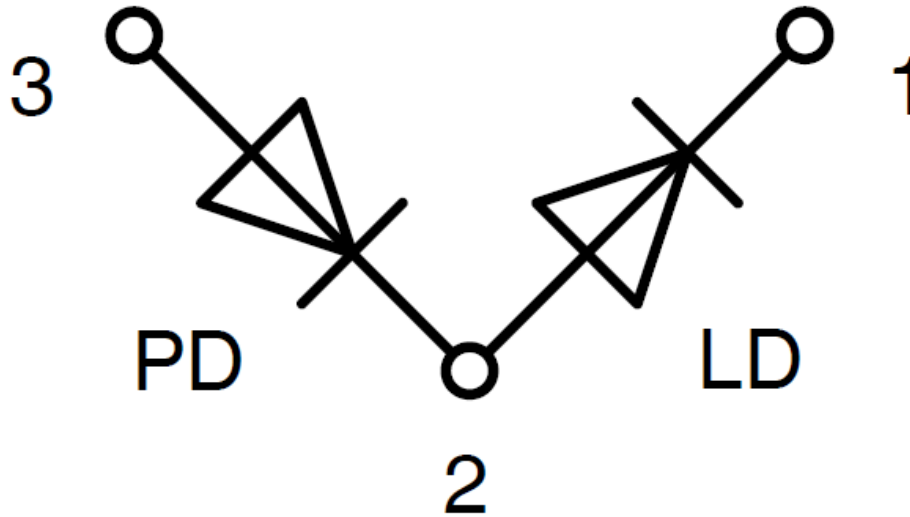


Approximate Weight: 310.0 mg

ESD advice: ATTENTION – Observe Precautions For Handling – Electrostatic Sensitive Device

DRAFT – For reference only. Subject to change without notice.

Electrical internal circuit



Pin	Description
PIN1	LD Cathode
PIN 2	LD Anode, PD Cathode (case)
PIN 3	PD Anode

Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related informations please visit www.osram-os.com/apnotes

Disclaimer

OSRAM OS assumes no liability whatsoever for any use of this document or its content by recipient including, but not limited to, for any design in activities based on this preliminary draft version. OSRAM OS may e.g. decide at its sole discretion to stop developing and/or finalising the underlying design at any time.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office.

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

In case Buyer – or Customer supplied by Buyer– considers using OSRAM OS components in product safety devices/applications or medical devices/applications, Buyer and/or Customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and Buyer and /or Customer will analyze and coordinate the customer-specific request between OSRAM OS and Buyer and/or Customer.

Glossary

- 1) **Operating/Forward current:** IF is measured with an internal reproducibility of $\pm 7\%$ (acc. to GUM with a coverage factor of $k = 3$).
- 2) **Reverse Operation:** Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.
- 3) **Wavelength:** λ_{peak} is measured with an internal reproducibility of ± 0.3 nm (acc. to GUM with a coverage factor of $k = 3$).
- 4) **Monitor current:** Monitor current refers to a reverse voltage of $V_{\text{RPD}} = 5$ V. Monitor current is for short time power reference purpose only. Not guaranteed for accuracy.
- 5) **Monitor current:** For reference only.
- 6) **Operating/Forward voltage:** VF is measured with an internal reproducibility of ± 0.05 V (acc. to GUM with a coverage factor of $k = 3$).
- 7) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 8) **Testing temperature:** $T_A = 25^\circ\text{C}$
- 9) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimensions are specified in mm.

Revision History

Version	Date	Change
---------	------	--------

DRAFT – For reference only. Subject to change without notice.